A novel temperature and disturbance insensitive DAC calibration method
Bechthum, E.; Radulov, G.I.; van Roermund, A.H.M.

Published in:

DOI:
10.1109/ISCAS.2011.5937988

Published: 01/01/2011

Document Version
Publisher's PDF, also known as Version of Record (includes final page, issue and volume numbers)

Please check the document version of this publication:

• A submitted manuscript is the author's version of the article upon submission and before peer-review. There can be important differences between the submitted version and the official published version of record. People interested in the research are advised to contact the author for the final version of the publication, or visit the DOI to the publisher's website.
• The final author version and the galley proof are versions of the publication after peer review.
• The final published version features the final layout of the paper including the volume, issue and page numbers.

Link to publication

Citation for published version (APA):

General rights
Copyright and moral rights for the publications made accessible in the public portal are retained by the authors and/or other copyright owners and it is a condition of accessing publications that users recognise and abide by the legal requirements associated with these rights.

• Users may download and print one copy of any publication from the public portal for the purpose of private study or research.
• You may not further distribute the material or use it for any profit-making activity or commercial gain
• You may freely distribute the URL identifying the publication in the public portal ?

Take down policy
If you believe that this document breaches copyright please contact us providing details, and we will remove access to the work immediately and investigate your claim.
A novel temperature and disturbance insensitive DAC calibration method

Elbert Bechthum, Georgi Radulov, Arthur van Roermund
Eindhoven University of Technology, Department of Electrical Engineering, The Netherlands
Email: E.Bechthum@tue.nl

Abstract—This paper presents a new foreground DAC calibration method that is insensitive to temperature fluctuations and on-chip disturbances.

In the proposed current cell, the same number of unit transistors is always used, guaranteeing matched response for all current cells. These transistors are divided into two groups: a fixed group and a configurable group. The unit transistors in the configurable group can be interchanged with additional redundant unit transistors, such that the mismatch errors of the configurable group compensate the mismatch errors of the fixed group. Together they generate the needed output current. Thus all current cells feature matched temperature coefficients and dynamic response. For an exemplary 6+6bits segmented current steering DAC, the expected 99% yield INL improves with almost 3 bits while using only 30% additional unit transistors.

I. INTRODUCTION

The static DAC linearity, e.g. INL (Integral Non Linearity), is mainly limited by the finite matching of the DAC current source transistors. The mismatch between identically sized and biased transistors is given in (1) [1].

\[
\frac{\sigma_I}{T} = \left( A_\beta^2 + \frac{4A_{VT}^2}{(V_{GS} - V_T)^2} \right) \cdot \frac{1}{2WL} \tag{1}
\]

Using large devices \(W \cdot L\) reduces the random mismatch, but increases occupied area and hence increases the systematic mismatch and degrades high-frequency performance. The dynamic linearity, e.g. SFDR (Spurious Free Dynamic Range), is usually limited by the achieved static linearity, and further reduced at high speeds by the parasitic capacitances and resistances of the current source transistors. Therefore, to achieve high linearity at high speed, both small and accurate current source transistors are necessary.

To improve the DAC static linearity and to reduce the size of the DAC current source transistors, calibration of the mismatch errors of the DAC current sources can be used. An example of calibration in a Current Steering DAC (CSDAC) is shown in Fig. 1 [2]. For an analysis of different correction methods, see [3].

Two types of calibration strategies can be distinguished: foreground and background calibration. Background calibration is continuously running while the DAC is actively used [4]. It suffers from increased power consumption during operation and the output signal may be polluted by spurious emissions of the calibration activities. Foreground calibration is only active when the DAC is idle, e.g. at startup, and hence avoids the aforementioned disadvantages. However, discrepancies in the environment between calibration and use, e.g. temperature or supply voltage, can reduce the advantages of the calibration. In addition, the advantages of the existing calibration methods also reduce at high speeds [4].

The proposed foreground calibration method uses identical unit transistors in both the current source and the CalDAC to guarantee matched responses to disturbances and temperature variations. The current cell is calibrated by combining unit transistors with opposite mismatch within one current cell such that their combined mismatch is minimized.

The next section explains the temperature and disturbance sensitivity of the conventional calibration. In section III, a new CalDAC implementation and calibration algorithm is proposed which is insensitive to temperature variations and disturbances. Section IV shows simulation results.

II. TEMPERATURE AND DISTURBANCE DEPENDENCE

An exemplary schematic of a CSDAC using CalDAC calibration is shown in Fig. 1, which is used in [5] and [6]. In the current cell, named Calibrated Unit Element (CUE), transistor \(M_1\) is the main current source with output current \(I_{main}\). Due to process spreading and systematic mismatches, the value of \(I_{main}\) deviates from the nominal designed value \(I_{main,n}\), i.e. for the \(n\)-th current source \(I_{main,n} = I_{main} + I_{error,n}\). The CalDAC generates a correction current such that the output of the CUE \(I_{cue,n}\) equals the value of \(I_{cue}\).

In the example of Fig. 1, the state of transistors \(M_{3,off}\) and \(M_{3,on}\) decides if the CUE output current is either used for the normal operation of the DAC or connected to the Calibration circuit and measured for calibration.

An exemplary implementation of a conventional CalDAC is shown in Fig. 2 [6], [7]. The main current source \(M_1\) consists of \(M\) transistors. The CalDAC, consisting of transistors \(M_{cal,1}\) to \(M_{cal,N}\), adds the required correction current.
To achieve high post-calibration static linearity, the LSB of the CalDAC should be much smaller than the LSB of the DAC [8]. Therefore, the transistors of the CalDAC have a smaller overdrive voltage \( V_{GS} - V_T \) and also usually different width \( W \) and length \( L \) with respect to the main current source transistors. With the exemplary DAC of [6], measurements show that a relative correction step of \( I_{L_{SB,cor}} \) results in a 12 bits linearity and a relative correction step of \( I_{L_{SB,cor}} < 0.2 \) results in a 13 bits linearity [3].

\[ I_D = \frac{\mu C_{ov} W}{2L} (V_{GS} - V_T)^2 \] (2)

At high temperatures, the mobility of the carriers (\( \mu \)) decreases. Usually, a temperature independent current controls the output current of the DAC current source transistors. Therefore, at high temperatures, \( V_{GS} - V_T \) increases to compensate for the decreasing \( \mu \). Together with the matching equation of (1), it is clear that when the temperature increases, \( V_{GS} - V_T \) increases, the relative threshold mismatch decreases. Mismatch measurements of the existing DAC at high temperature confirm this analysis, see Fig. 3.

In the discussed conventional CUE, the mismatch of a main current source is compensated by the nominal value of the CalDAC output current, i.e. \( I_{cuy,n} = I_{main} + I_{error,n} + I_{cor,n} \). \( I_{main} \) and \( I_{cor,n} \) are set by temperature independent references, while \( I_{error,n} \) is temperature dependent. Therefore, the temperature coefficient of \( I_{cuy,n} \) depends on the ratio between \( I_{cuy,n} \) and \( I_{error,n} \). Fig. 4 shows the buildup of the output current of two exemplary CUEs. The CUEs are calibrated at \( T = 25^\circ C \), but for \( T \neq 25^\circ C \), the CalDAC calibration is not valid.

To quantify the temperature dependence, a simple transistor level simulation based on [6] is performed. Two calibrated CUEs with threshold voltage mismatch between each other are simulated over a temperature range of \(-50^\circ C \) to \( 125^\circ C \). The temperature dependence of the CUEs output current difference, i.e. \( error_{Low} - error_{High} \), can be as large as 8 CalDAC LSBs, which is 1.3% of the CUE output current. This phenomenon is confirmed by INL and SFDR measurements of an existing DAC [8].

### B. Disturbance response

Next to the discussion about the temperature dependence of the calibration, the CUEs also exhibit a calibration dependent disturbance response. It can easily be argued that two CUEs with different ratios between main current and CalDAC current have different responses to a disturbance on the gate node of the CalDAC current sources. This also holds for disturbances on other nodes of the CUEs. For an exemplary DAC, implemented in a CMOS 65nm process, with two current cells with different correction currents and a disturbance at \( V_{bheat} \) of Fig. 2, the difference in the output current response of the two current cells is shown by the top waveform of Fig. 5. The cell dependent response difference of more than 50% will certainly introduce input code dependent behavior, which results in spurious emissions, significantly reducing the SFDR.

### III. PROPOSED NEW CALIBRATION METHOD

To match the response of the correction hardware to temperature and on-chip disturbances, and hence extend the advantages of the foreground calibration, a new calibration method is proposed.

In the proposed CUE, the same number of unit transistors \( M \) is used in every CUE. These \( M \) transistors are divided in two groups, \( M - K \) unit transistors in the fixed group...
and $K$ unit transistors in the configurable group. The $K$ unit transistors in the configurable group can be interchanged with $X$ additional redundant unit transistors, such that the mismatch of the configurable group transistors compensate the mismatch of the fixed group and together generate the desired output current.

A novel principle is the use of identical unit transistors for both the fixed group and the configurable group, sharing a common bias voltage, providing a matched response for every CUE in the DAC. Another novel concept is to compensate the mismatch of the fixed group of transistors in the current cell with the mismatch of the configurable group transistors, generating a temperature stable calibration.

### A. Hardware

A schematic overview of the new CalDAC implementation is shown in Fig. 6. The $M - K$ main current source transistors provide the fixed current $I_{\text{main}}$. $K$ units in the group of $P$ unit transistors in the CalDAC are switched on to generate the correction current $I_{\text{cor}}$. The value of $X$ defines the added amount of redundant current sources with respect to the $M$-transistor intrinsic current cell. The value of $P$ is an indication of the added layout complexity, since every transistor in the CalDAC is controlled separately.

![Fig. 6. Proposed CalDAC with common transistor dimensions and biasing](image)

### B. Algorithm

The algorithm to find the optimal correction for a current source is explained using a segmented DAC architecture, of which the Least Significant Bits (LSBs) are implemented using binary current cells and the Most Significant Bits (MSBs) are implemented with unary coded current cells. Note that the described method can also be applied to a fully unary or binary coded DAC. Two different calibration methods are used for the unary current cells and the binary current cells, which are described separately.

#### 1) Unary current cells:

The principle of the calibrating algorithm of one CUE is to select which transistors of the CalDAC should be switched on such that $I_{\text{cue}}$ is properly corrected. The first step in the algorithm is to sort the transistors in the CalDAC according to their output amplitude and then switch on $K$ of the highest amplitude transistors. Fig. 7 gives an example, where $M = 8$, $K = 3$ and $X = 3$. The top figure shows the output amplitude of the unit transistors (which are named $a$-$k$), and gives the first step.

The second step in the algorithm is to swap transistors between the on-group and the off-group until the total output current becomes less than the reference. The top diagram of Fig. 7 indicates the first three swap actions (named 1-3). The bottom diagram gives the resulting total output current of the CUE for the initial state (named 0) and after each swap action. The algorithm will stop after swap step 3, because the total output current is less than the reference $I_{\text{ref}}$.

For the calibration of the unary current cells, the reference consists of the sum of all binary current cells and one LSB current source as in [7]. Therefore, the binary current cells should be calibrated before the unary current cell calibration. The main hardware component necessary to implement the algorithm for the unary current cells is a comparator to sort the transistors and compare the reference and the CUE total output current. The algorithm can be realized as a simple Finite State Machine (FSM).

#### 2) Binary current cells:

The algorithm to calibrate the binary current cells is largely identical to the algorithm for the unary current cells. For the calibration of $N_{\text{lsb}}$ binary current cells in one DAC, $N_{\text{lsb}}$ reference currents are required, with a ratio of 2 between two successive references. Since exact current ratios are difficult to implement in the analog domain, the complete binary calibration algorithm is implemented in the digital domain. Therefore, all unit transistor currents are measured using an Analog to Digital Converter (ADC), and all transistor sorting, swapping and output current calculation can be done digitally. To be insensitive to gain and offset errors of the ADC, the main current source of the binary current cells is omitted ($M - K = 0$). Instead, the current cell output current is constructed using the separately measured unit transistors of the CalDAC. The algorithm is insensitive to the ADC offset and gain error since all unit transistors share the same ADC.
errors with equal relative importance.

For the binary calibration, the simple comparator check in the unary current cell calibration is replaced by a check if the difference between the reference and the total output current is minimal. The reference for the binary current cell calibration is generated by separately measuring all CalDAC transistors of the complete DAC with the ADC, computing the average and multiplying by the corresponding power of two.

The necessary hardware to implement the binary current cell calibration is the ADC and a FSM. The ADC does not need to be fast or accurate and is implemented as a Successive Approximation (SAR) ADC [6], [7] with 5 bits linearity. The additional area for the ADC and the FSM is negligible compared to the area of the current source array.

IV. SIMULATION RESULTS

A. Algorithm

The presented new calibration algorithm is validated using a Matlab model of a 6+6 (unary + binary) bits segmented DAC. All current cells are based on the same unit transistor. The LSB current cell consists of 1 transistor, the next current cell of 2 transistors, etc. Thus, the unary current cell has a weight of $2^{N_{LSB}}$ LSB, and hence consists of $M = 64$ transistors.

There is a trade-off between the additional hardware and hardware complexity in the choice for $K$ and $X$. The achieved improvement between the intrinsic INL and the calibrated INL depends on $K$ and $X$. Monte Carlo simulations of 1200 DACs per one simulation point are executed to investigate the effects of using different values for $K$ and $X$ on the 99% yield INL.

First, these simulation show that with a fixed number of CalDAC transistors ($P$), the highest improvement of INL is achieved when $K = X$, since then the number of possible combinations is maximized. For different values of $K$, $X$ and unit transistor matching, the 99% yield INL values, with respect to 12 bits accuracy, are shown in Fig. 8. It is clear that using more transistors in the CalDAC results in more possibilities for the algorithm and hence higher improvement when applying the calibration method. It is also observed that the improvement between the intrinsic INL and the calibrated INL is constant when the values of $K$ and $X$ are fixed.

Fig. 8. Matlab simulations showing the matching- and configuration-dependent 99% yield INL of the new calibration method

When for the exemplary 6+6bits DAC, 12 bit linearity is required and 99% yield for the INL specification, the combination of 3% unit transistor matching and a CalDAC with $K = X = 20$ results in an improvement of static linearity from 9.4 bits to 12.2 bits, while only increasing the current source area with approximately 30%.

B. Temperature response

To investigate the temperature coefficient of the proposed calibration method, the same transistor level simulation of section II is performed. After calibration, the temperature dependence of the difference between the two currents is less than 0.001% of the total output current over the complete temperature range, which is 1000 times lower than the conventional CalDAC calibration. Thus, the proposed calibration principle results in a temperature stable calibration.

C. Disturbance response

The same number of transistors is switched on in every CUE. Therefore, every CUE has approximately the same response to disturbances, independent of the correction current, which guarantees that the advantages of the calibration are also present at high speeds. For a disturbance at the gate node of the current source transistors ($V_{ds}$ in Fig. 6), the difference in output response of the two exemplary CUEs is shown as the bottom waveform in Fig. 5. Over the complete frequency band, the difference in response between the two CUEs is less than -70dB. Since the response difference is magnitudes lower than the conventional CalDAC, it is expected that the spurious emissions due to on-chip disturbances are significantly reduced.

V. CONCLUSION

The proposed novel calibration method overcomes the problems with the cell-dependent temperature coefficients of the Calibrated Unit Elements. Also the cell-dependent response to disturbances is reduced. Due to the reduction of these two cell-dependent responses, the spectral purity of the DAC output signal should be improved. The new calibration algorithm provides opportunities to improve the post calibration INL of a DAC. For an exemplary 6+6bits segmented current steering DAC, the expected 99% yield INL improves with almost 3 bits when using only 30% additional current cell area. The proposed new calibration method will obviate the need for background calibration, while also providing calibration advantages to high DAC speeds.

REFERENCES